



ECH8660

Power MOSFET

30V, 4.5A, 59mΩ, -30V, -4.5A, 59mΩ, Complementary Dual ECH8

ON Semiconductor®

<http://onsemi.com>

Features

- The ECH8660 incorporates an N-channel MOSFET and a P-channel MOSFET that feature low ON-resistance and high-speed switching, thereby enabling high-density mounting
- 4V drive
- Halogen free compliance

Specifications

Absolute Maximum Ratings at Ta=25°C

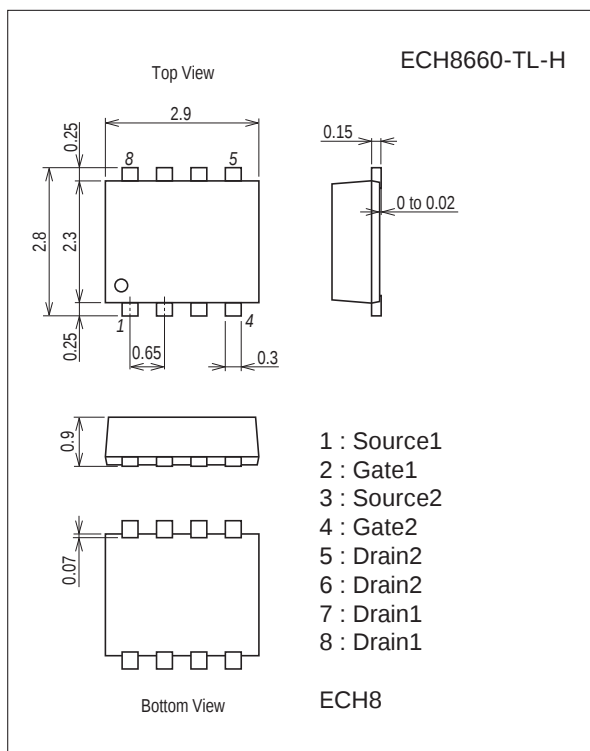
Parameter	Symbol	Conditions	N-channel	P-channel	Unit
Drain-to-Source Voltage	V _{DSS}		30	-30	V
Gate-to-Source Voltage	V _{GSS}		±20	±20	V
Drain Current (DC)	I _D		4.5	-4.5	A
Drain Current (Pulse)	I _{DP}	PW≤10μs, duty cycle≤1%	30	-30	A
Allowable Power Dissipation	P _D	When mounted on ceramic substrate (1200mm²×0.8mm) 1unit	1.3		W
Total Dissipation	P _T	When mounted on ceramic substrate (1200mm²×0.8mm)	1.5		W
Channel Temperature	T _{ch}		150		°C
Storage Temperature	T _{stg}		-55 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

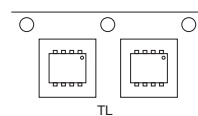
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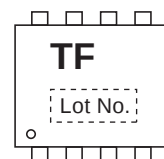
Product & Package Information

- Package : ECH8
- JEITA, JEDEC : -
- Minimum Packing Quantity : 3,000 pcs./reel

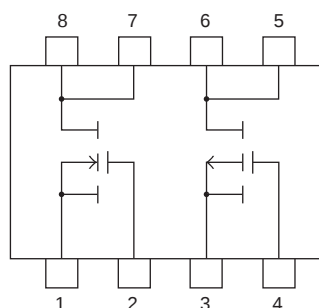
Packing Type : TL



Marking



Electrical Connection

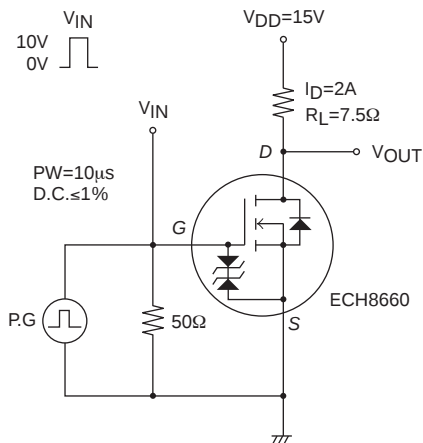


Electrical Characteristics at Ta=25°C

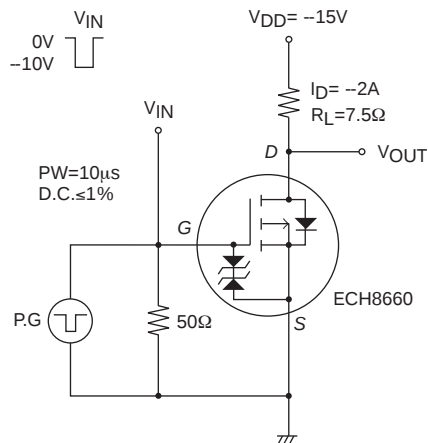
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
[N-channel]						
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=30V, VGS=0V			1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	VDS=10V, ID=2A	1	1.66		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=2A, VGS=10V		45	59	mΩ
	RDS(on)2	ID=1A, VGS=4.5V		85	119	mΩ
	RDS(on)3	ID=1A, VGS=4V		110	155	mΩ
Input Capacitance	Ciss	VDS=10V, f=1MHz		240		pF
Output Capacitance	Coss	VDS=10V, f=1MHz		45		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		30		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		6.2		ns
Rise Time	tr	See specified Test Circuit.		11		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		17		ns
Fall Time	tf	See specified Test Circuit.		7.5		ns
Total Gate Charge	Qg	VDS=10V, VGS=10V, ID=4.5A		4.4		nC
Gate-to-Source Charge	Qgs	VDS=10V, VGS=10V, ID=4.5A		1.1		nC
Gate-to-Drain “Miller” Charge	Qgd	VDS=10V, VGS=10V, ID=4.5A		0.64		nC
Diode Forward Voltage	VSD	IS=4.5A, VGS=0V		0.84	1.2	V
[P-channel]						
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=-1mA, VGS=0V	-30			V
Zero-Gate Voltage Drain Current	IDSS	VDS=-30V, VGS=0V			-1	μA
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0V			±10	μA
Cutoff Voltage	VGS(off)	VDS=-10V, ID=-1mA	-1.2		-2.3	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-2A	2.5	4.2		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=-2A, VGS=-10V		45	59	mΩ
	RDS(on)2	ID=-1A, VGS=-4.5V		71	100	mΩ
	RDS(on)3	ID=-1A, VGS=-4V		82	115	mΩ
Input Capacitance	Ciss	VDS=-10V, f=1MHz		430		pF
Output Capacitance	Coss	VDS=-10V, f=1MHz		105		pF
Reverse Transfer Capacitance	Crss	VDS=-10V, f=1MHz		75		pF
Turn-ON Delay Time	td(on)	See specified Test Circuit.		7.5		ns
Rise Time	tr	See specified Test Circuit.		26		ns
Turn-OFF Delay Time	td(off)	See specified Test Circuit.		45		ns
Fall Time	tf	See specified Test Circuit.		35		ns
Total Gate Charge	Qg	VDS=-10V, VGS=-10V, ID=-4.5A		10		nC
Gate-to-Source Charge	Qgs	VDS=-10V, VGS=-10V, ID=-4.5A		2.0		nC
Gate-to-Drain “Miller” Charge	Qgd	VDS=-10V, VGS=-10V, ID=-4.5A		2.5		nC
Diode Forward Voltage	VSD	IS=-4.5A, VGS=0V		-0.85	-1.2	V

Switching Time Test Circuit

[N-channel]

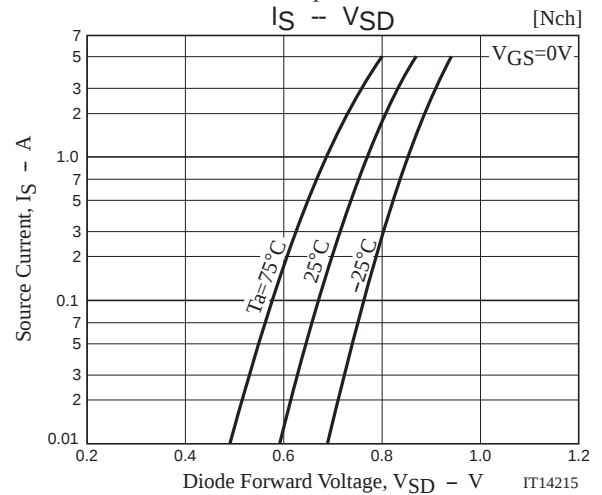
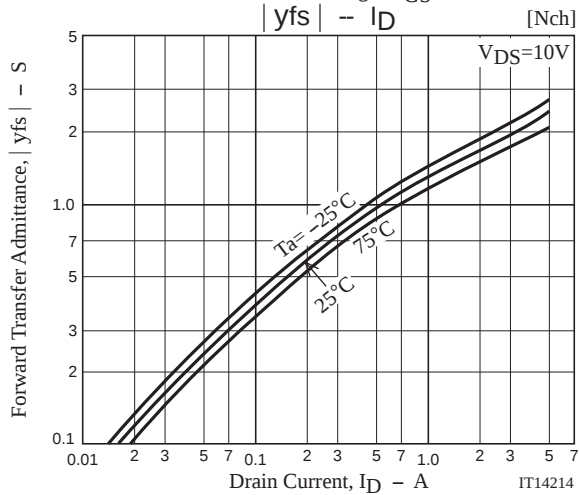
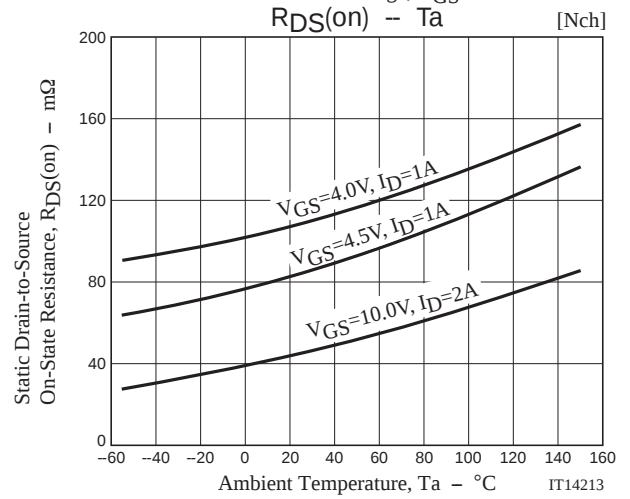
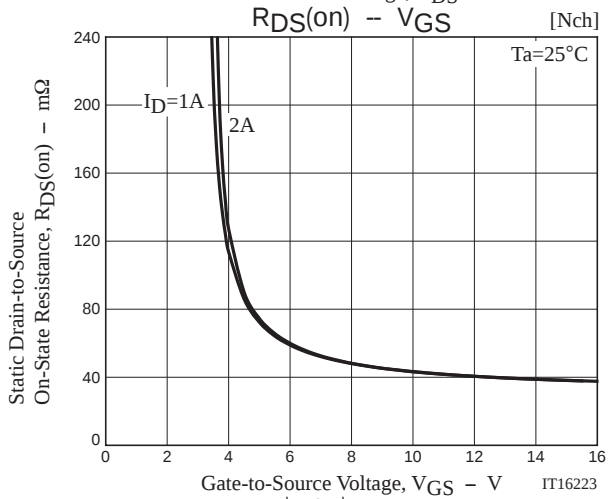
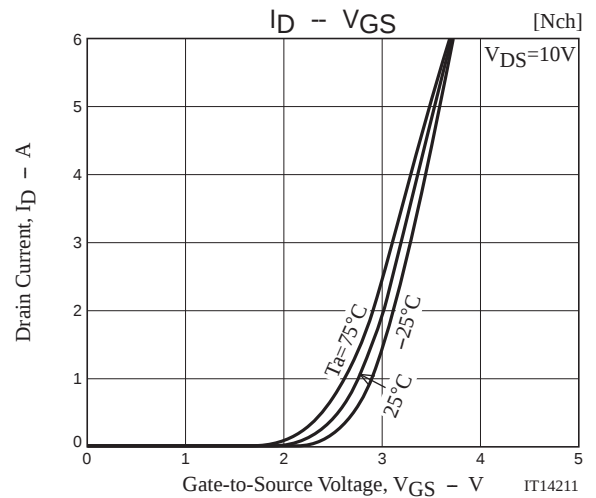
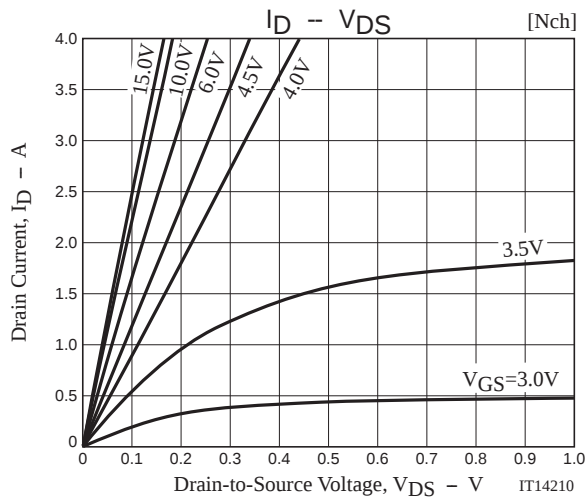


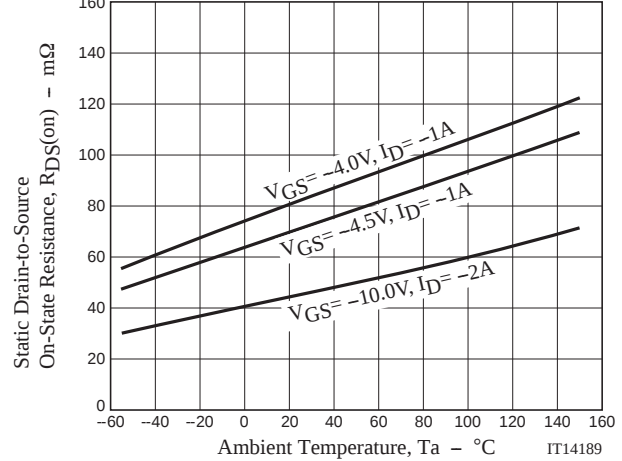
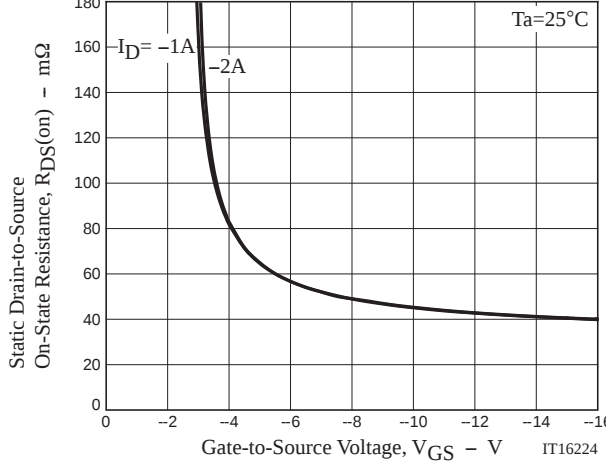
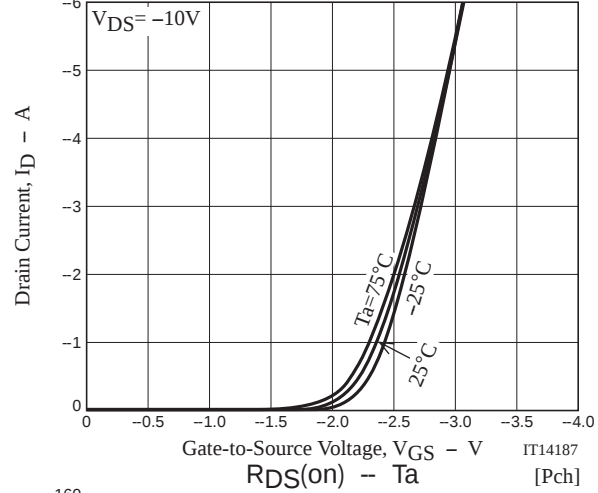
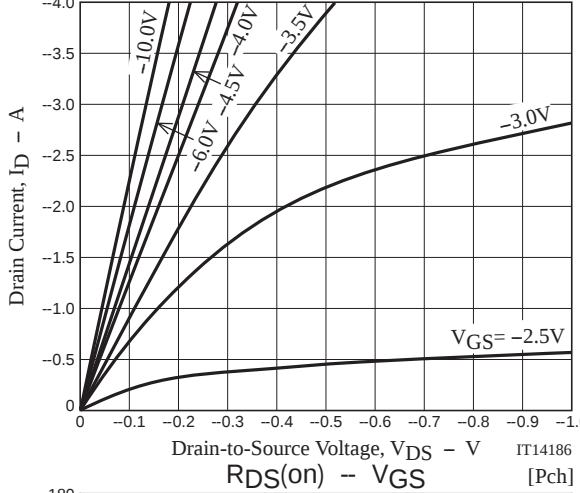
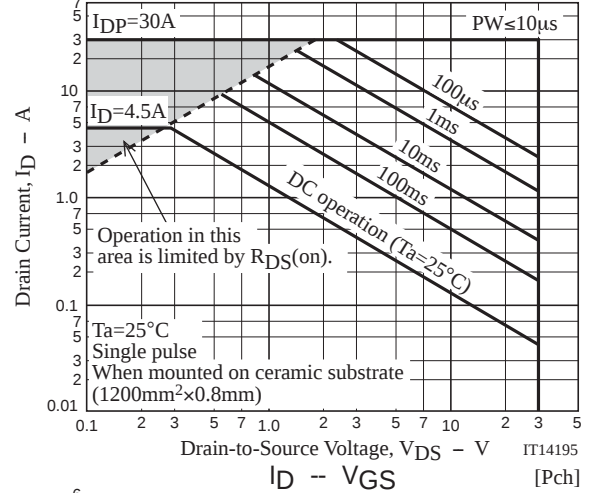
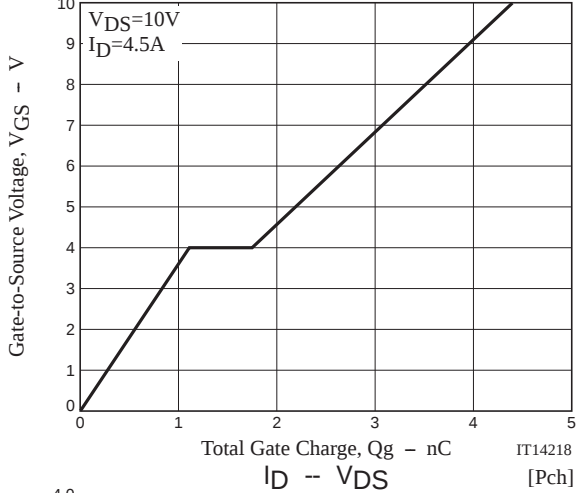
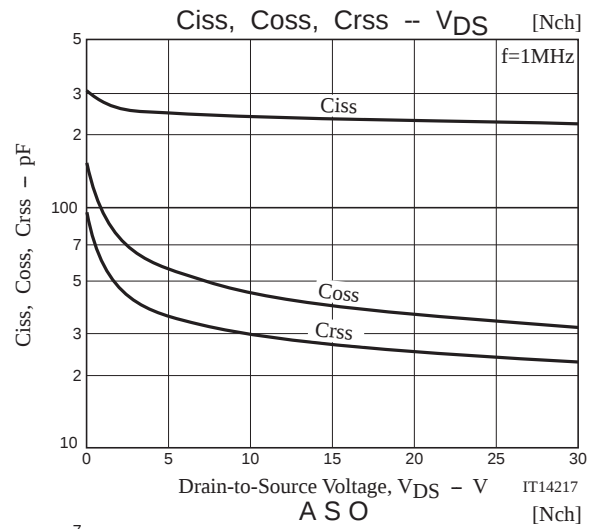
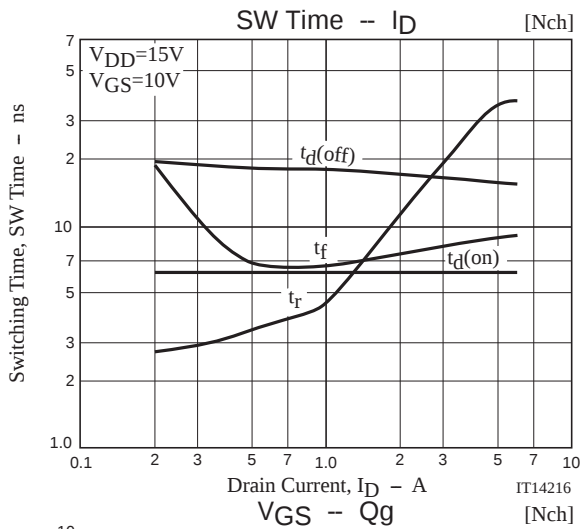
[P-channel]

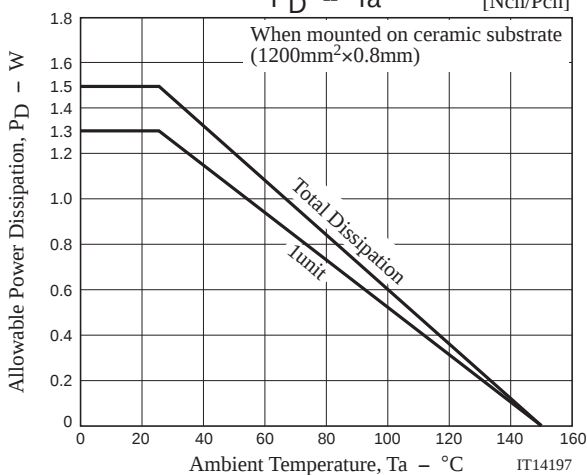
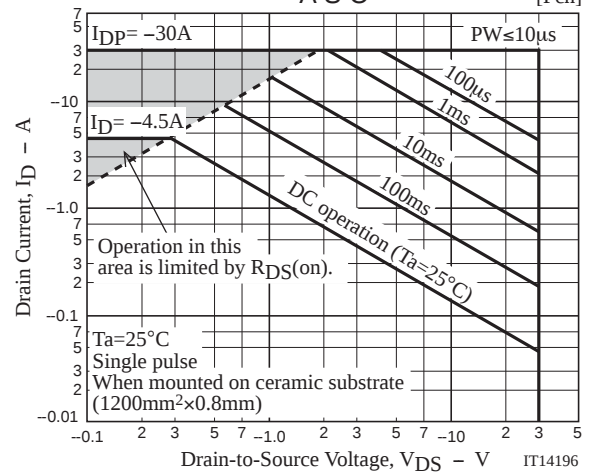
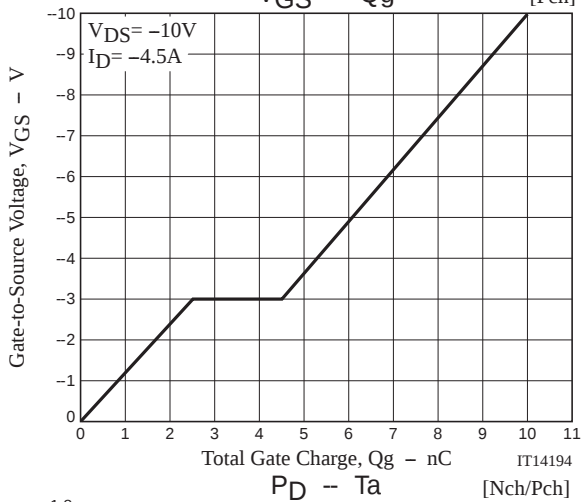
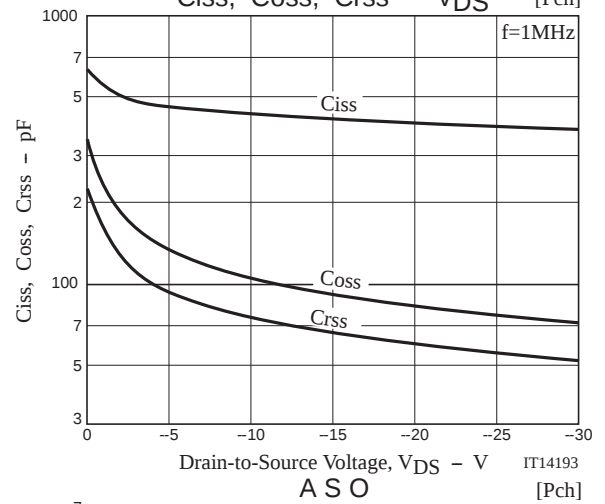
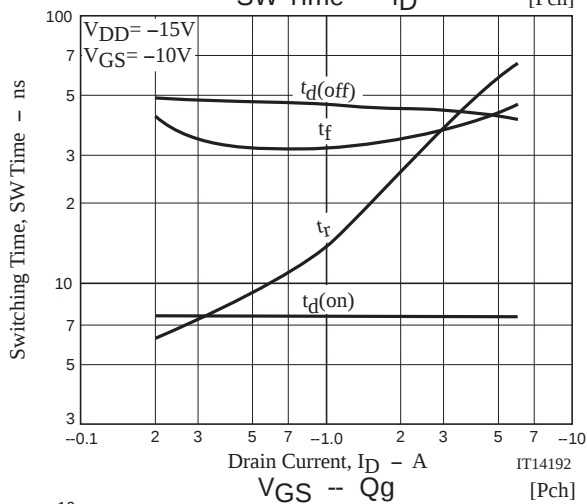
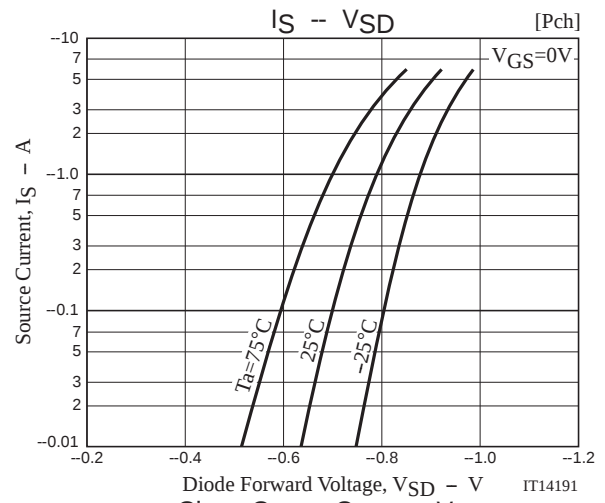
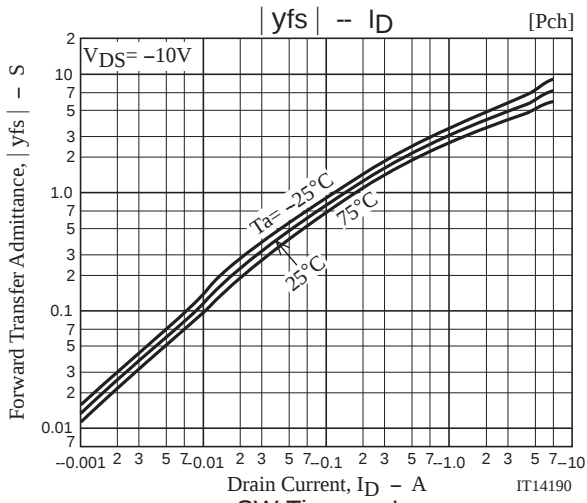


Ordering Information

Device	Package	Shipping	memo
ECH8660-TL-H	ECH8	3,000pcs./reel	Pb-Free and Halogen Free







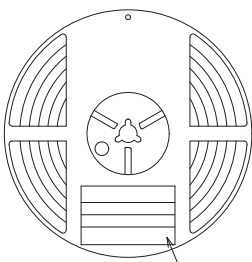
Embossed Taping Specification

ECH8660-TL-H

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
ECH8	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label

Type No.
LOT No.
Quantity
Origin

Reel label, Inner box label
(unit:mm)

(P) TYPE	000000000
(1) LOT	00
(Q) QTY	0,000 (1) LEAD FREE *
(2) SPECIAL	
	20722005310C
	ASSEMBLY:**** (DIFFUSION:****)

Outer box label

It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.

TYPE CODE	00000000000000000000
TYPE	00000000
QTY	0,000 PCS (1) LEAD FREE *
LOT	00000000
PACKAGE	00000000
SPECIAL	
	20722005310C
	ASSEMBLY:**** (DIFFUSION:****)

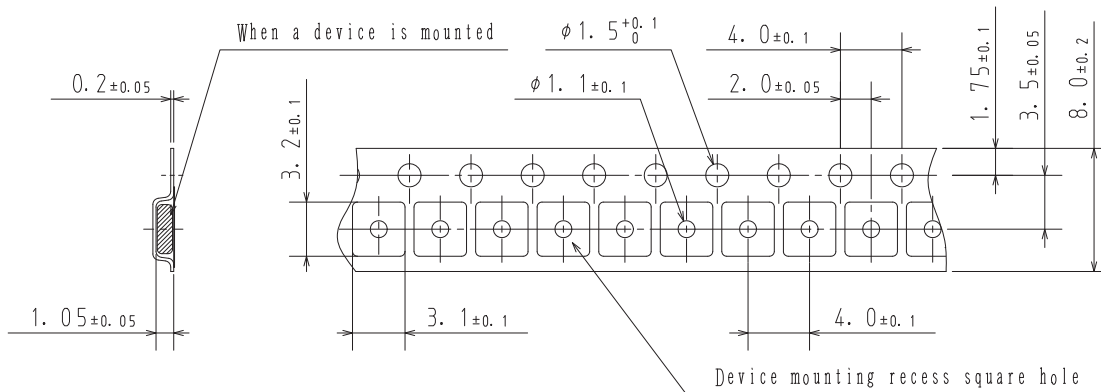
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

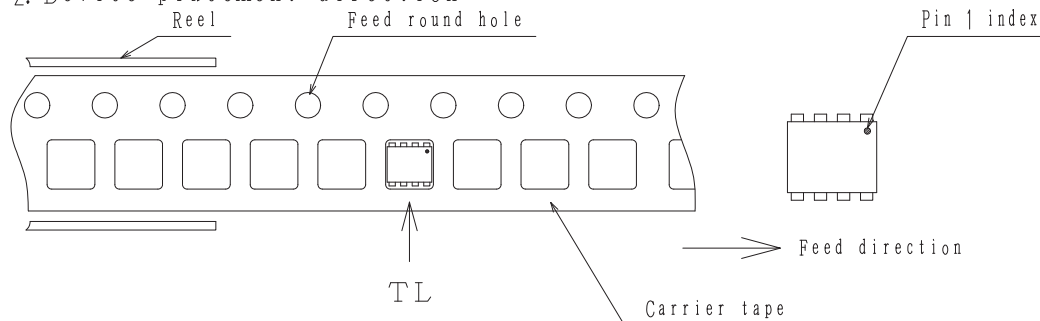
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)

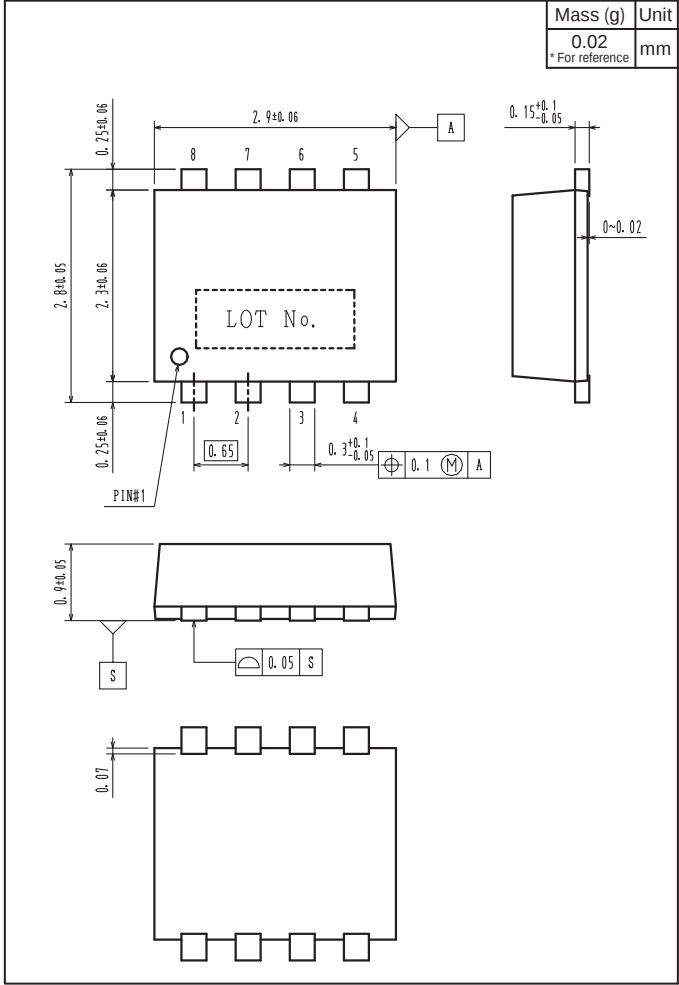


2-2. Device placement direction

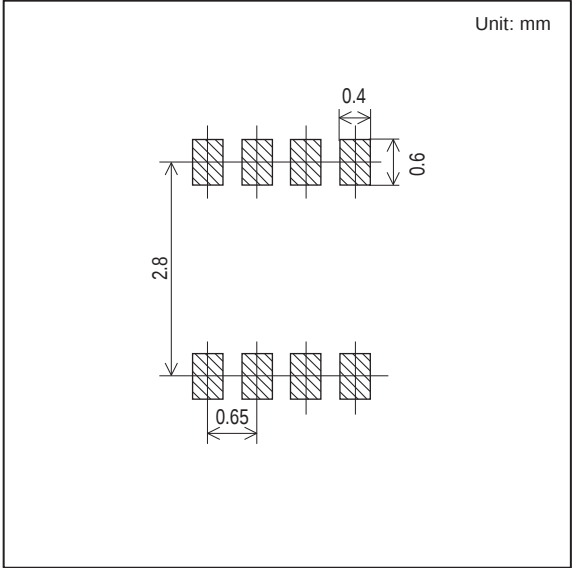


Those with pin 1 index on the feed hole side.....TL

Outline Drawing
ECH8660-TL-H



Land Pattern Example



Note on usage : Since the ECH8660 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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